

**isc Silicon PNP Power Transistor**

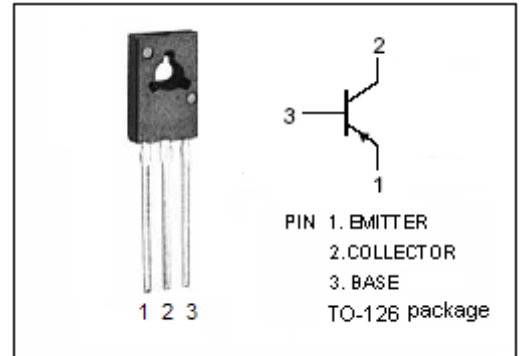
**2SA1507**

**DESCRIPTION**

- High Collector-Emitter Breakdown Voltage-  
 $V_{(BR)CEO} = -160V$  (Min)
- Large Current Capacity
- Complement to Type 2SC3902

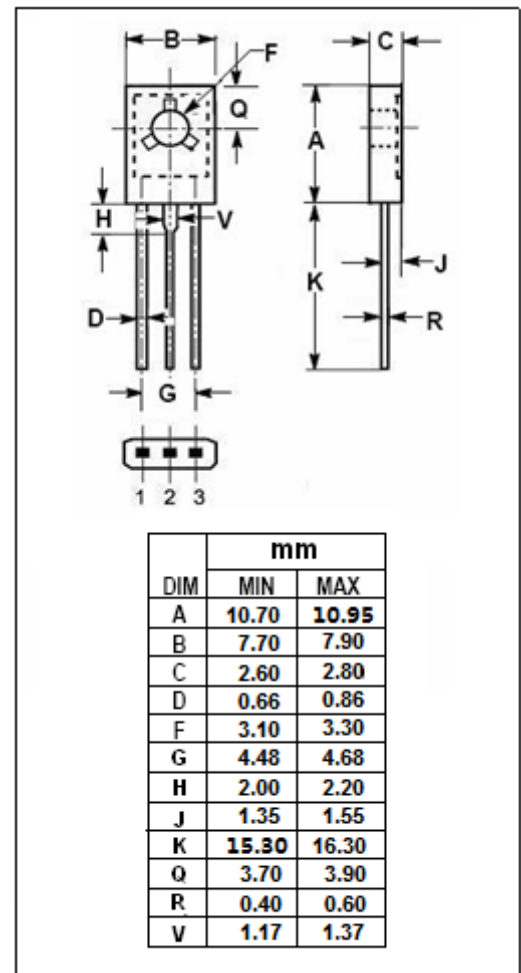
**APPLICATIONS**

- Designed for use in color TV audio output, converters and inverters.



**ABSOLUTE MAXIMUM RATINGS(Ta=25°C)**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	-180	V
$V_{CEO}$	Collector-Emitter Voltage	-160	V
$V_{EBO}$	Emitter-Base Voltage	-6.0	V
$I_C$	Collector Current-Continuous	-1.5	A
$I_{CM}$	Collector Current-Peak	-2.5	A
$P_C$	Collector Power Dissipation @ $T_a=25^\circ C$	1.5	W
	Total Power Dissipation @ $T_C=25^\circ C$	10	
$T_J$	Junction Temperature	150	$^\circ C$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ C$



## isc Silicon PNP Power Transistor

2SA1507

## ELECTRICAL CHARACTERISTICS

 $T_C=25^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = -10\mu\text{A}; I_E = 0$	180			V
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -1\text{mA}; R_{BE} = \infty$	160			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = -10\mu\text{A}; I_C = 0$	6			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -500\text{mA}; I_B = -50\text{mA}$			-0.5	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = -500\text{mA}; I_B = -50\text{mA}$			-1.2	V
$I_{CBO}$	Collector Cutoff Current	$V_{CB} = -120\text{V}; I_E = 0$			-0.1	$\mu\text{A}$
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = -4\text{V}; I_C = 0$			-0.1	$\mu\text{A}$
$h_{FE-1}$	DC Current Gain	$I_C = -100\text{mA}; V_{CE} = -5\text{V}$	100		400	
$h_{FE-2}$	DC Current Gain	$I_C = -10\text{mA}; V_{CE} = -5\text{V}$	90			
$f_T$	Current-Gain—Bandwidth Product	$I_C = -50\text{mA}; V_{CE} = -10\text{V}$		120		MHz
$C_{OB}$	Output Capacitance	$I_E = 0; V_{CB} = -10\text{V}; f = 1.0\text{MHz}$		22		pF

## Switching Times

$t_{on}$	Turn-on Time	$I_C = -0.7\text{A}, R_L = 14.3\Omega,$ $I_{B1} = -I_{B2} = -70\text{mA}, V_{CC} = -100\text{V};$ $P_W = 20\mu\text{s}; \text{Duty Cycle} \leq 1\%$		0.04		$\mu\text{s}$
$t_{stg}$	Storage Time			0.7		$\mu\text{s}$
$t_f$	Fall Time			0.04		$\mu\text{s}$

◆  $h_{FE-1}$  Classifications

R	S	T
100-200	140-280	200-400